



N-Channel Q_g , Fast Switching MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
30	0.0095 at V _{GS} = 10 V	12.5		
	0.0135 at V _{GS} = 4.5 V	10.5		

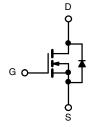
FEATURES

- Halogen-free According to IEC 61249-2-21 **Definition**
- Extremely Low Q_{gd} for Switching Losses
 TrenchFET[®] Power MOSFET
- 100 % R_q Tested
- Compliant to RoHS Directive 2002/95/EC



APPLICATIONS

- High-Side DC/DC Conversion
 - Notebook
 - Server



N-Channel MOSFET

SO-8 D D D Top View

Ordering Information: Si4390DY-T1-E3 (Lead (Pb)-free)

Si4390DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS (T	_A = 25 °C, unle	ess otherwise	noted)		
Parameter	Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V_{DS}	30		V
Gate-Source Voltage		V_{GS}	± 20		V
Continuous Drain Current (T,I = 150 °C) ^a	T _A = 25 °C	- I _D	12.5	8.5	Α
Continuous Diain Current (1, = 150 °C)	T _A = 70 °C		10	6.8	
Pulsed Drain Current		I _{DM}	20		A
Continuous Source Current (Diode Conduction) ^a		I _S	2.7	1.3	
Maximum Power Dissipation ^a	T _A = 25 °C	D	3.0 1.4	1.4	W
Maximum Fower Dissipation	T _A = 70 °C	P_{D}	1.9	0.9	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	t ≤ 10 s	D	32	42	
Waximum Junction-to-Ambient	Steady State	- R _{thJA}	68	90	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	15	20	

Notes:

a. Surface mounted on 1" x 1" FR4 board.

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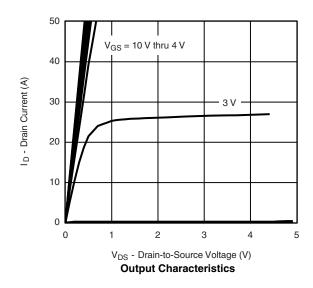
SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.8		2.8	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zara Cata Valtaga Drain Current	1	V _{DS} = 30 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α	
	В	V _{GS} = 10 V, I _D = 12.5 A		0.0075	0.0095	0	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 10.5 \text{ A}$		0.0105	0.0135	Ω	
Forward Transconductance ^a	g _{fs}	V _{DS} = 15 V, I _D = 12.5 A		38		S	
Diode Forward Voltage ^a	V_{SD}	$I_S = 2.7 \text{ A}, V_{GS} = 0 \text{ V}$		0.7	1.1	V	
Dynamic ^b							
Total Gate Charge	Q_g			10	15		
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 12.5 \text{ A}$		3.5		nC	
Gate-Drain Charge	Q_{gd}			2.1			
Gate Resistance	R_g		0.2	0.8	1.4	Ω	
Turn-On Delay Time	t _{d(on)}			16	30		
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		6	12		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		43	70	ns	
Fall Time	t _f			14	25	110	
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = 2.7 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		35	60		

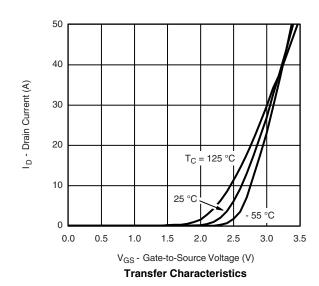
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

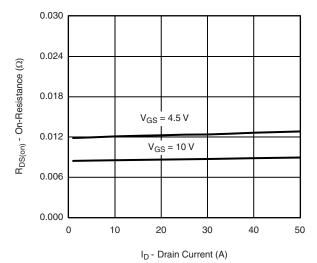




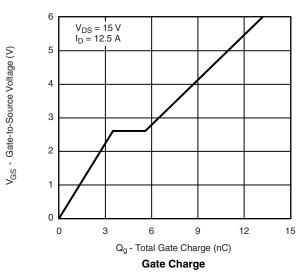


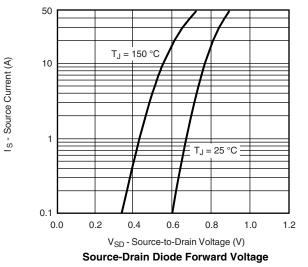


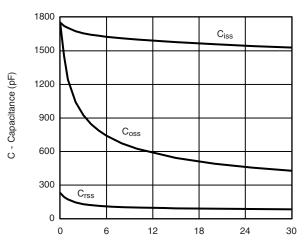
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



On-Resistance vs. Drain Current

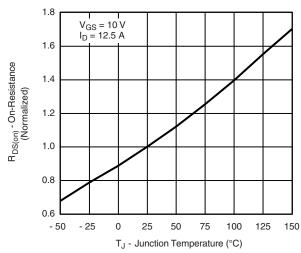




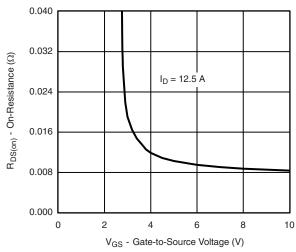


V_{DS} - Drain-to-Source Voltage (V)





On-Resistance vs. Junction Temperature

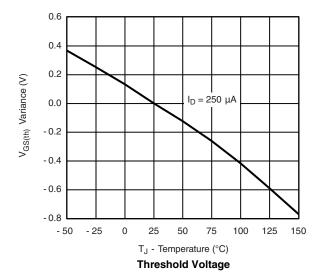


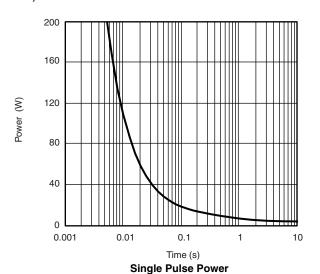
On-Resistance vs. Gate-to-Source Voltage

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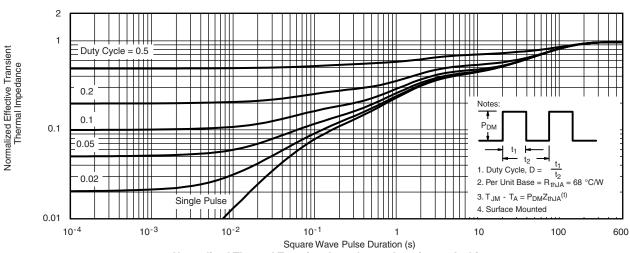
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



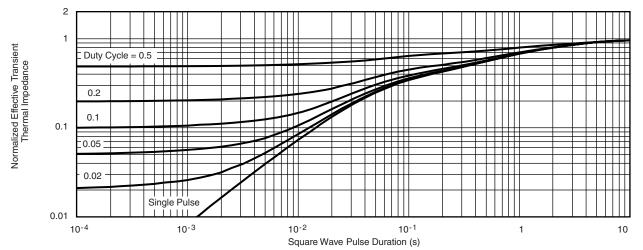


 $(V) \text{ the polynomial problem} \\ (V) \text{ the polynomial problem}$





TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72150.



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIMETERS INCHES			HES		
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27 BSC		0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
FCN: C-06527-Bey 11-Sen-06						

DWG: 5498

Document Number: 71192 www.vishay.com 11-Sep-06



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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